

STPS30H60-Y

Automotive power Schottky rectifier

Datasheet – production data

Features

- High junction temperature capability
- Avalanche rated
- Low leakage current
- Good trade-off between leakage current and forward voltage drop
- High frequency operation
- AEC-Q 101 qualified

Description

Dual centre tab Schottky rectifier suited for high frequency switch mode power supply.

Packaged in D²PAK, this device is designed for use in automotive applications. In these applications this device provides a good margin between the remaining voltage applied on the diode and the voltage capability of the diode.

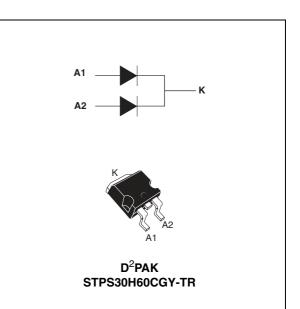


Table 1. Device summary

Symbol	Value
I _{F(AV)}	2 X 15 A
V _{RRM}	60 V
Тj	175 °C
V _{F (typ)}	0.535 V

This is information on a product in full production.

1 Characteristics

Table 2. Absolute ratings (limiting values per diode)

Symbol	Parameter			Value	Unit
V _{RRM}	Repetitive peak reverse voltage			60	V
I _{F(RMS)}	Forward rms current			30	А
1	Average forward current, $\delta = 0.5$	T _c = 155 °C	Per diode	15	А
^I F(AV)			Total package	30	~
I _{FSM}	Surge non repetitive forward current	rd current t _p = 10 ms sinusoidal			А
P _{ARM}	Relative peak avalanche power	T _j = 125 °C	t _p = 10 μs	715	W
Тj	Operating junction temperature range ⁽¹⁾			-40 to + 175	°C
T _{stg}	Storage temperature range			-65 to + 175	°C

1. $\frac{dPtot}{dT_j} < \frac{1}{Rth(j-a)}$ condition to avoid thermal runaway for a diode on its own heatsink

Table 3.Thermal parameters

Symbol	Parameter	Value	Unit
Б	Per diode	1.5	
R _{th(j-c)}	Junction to case Total	0.8	°C/W
R _{th(c)}	Coupling	0.1	

Table 4. Static electrical characteristics

Symbol	Parameter	Test conditions		Min.	Тур.	Max.	Unit
I _B ⁽¹⁾	Reverse leakage current	T _j = 25 °C	V _V			60	μA
'R` ´	neverse leakage current	T _j = 125 °C	$V_{R} = V_{RRM}$		8	25	mA
		T _j = 25 °C	– I _F = 7.5 A			550	
	Forward voltage drop	T _j = 125 °C			435	470	- mV
V _F ⁽²⁾		T _j = 25 °C	I _F = 15 A			660	
VF`'		T _j = 125 °C			535	570	
		T _j = 25 °C	I _F = 30 A			820	
		T _j = 125 °C			635	690	

1. Pulse test: $t_p = 5 \text{ ms}, \delta < 2\%$

2. Pulse test: t_p = 380 $\mu s, \, \delta$ < 2%

To evaluate the conduction losses use the following equation:

 $P = 0.45 \text{ x } I_{F(AV)} + 0.008 \text{ x } {I_{F}}^{2}_{(RMS)}$

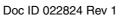




Figure 1. **Conduction losses versus** average forward current

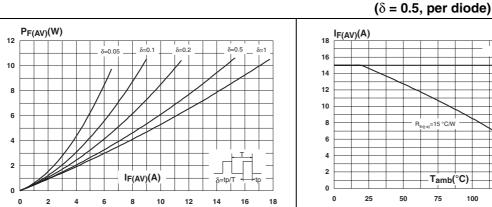


Figure 2.

Figure 3. Normalized avalanche power derating versus pulse duration

Figure 4. **Relative variation of thermal** impedance junction to case versus pulse duration

Tamb(°C)

100

125

150

175

75

50

. 15 °C/W

Average forward current versus

ambient temperature

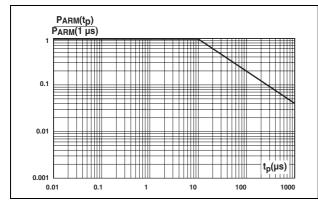


Figure 5. **Reverse leakage current versus** reverse voltage applied (typical values, per diode)

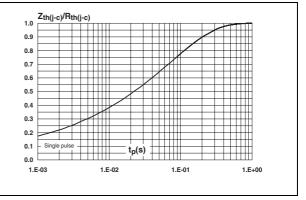


Figure 6. Junction capacitance versus reverse voltage applied (typical values, per diode)

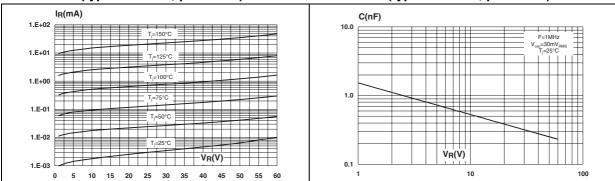
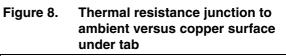
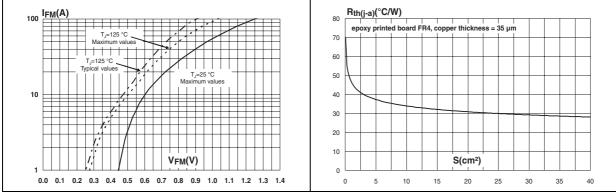


Figure 7. Forward voltage drop versus forward current (per diode)







2 Package information

- Epoxy meets UL94, V0
- Cooling method: by conduction (C)

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: <u>www.st.com</u>. ECOPACK[®] is an ST trademark.

Table 5. D²PAK dimensions

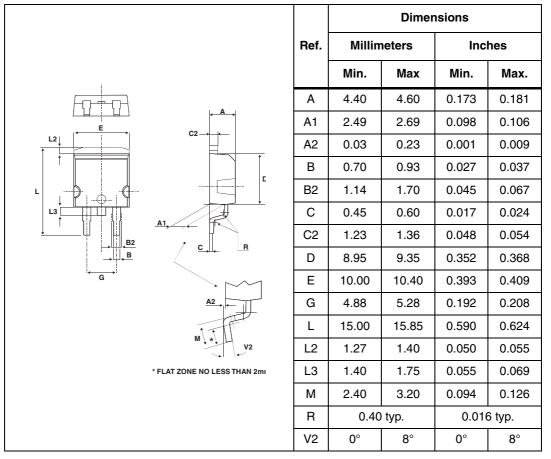
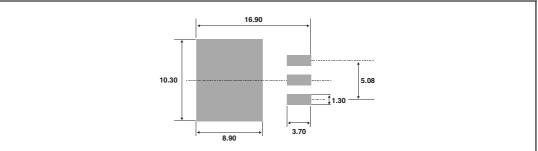


Figure 9. Footprint (dimensions in millimeters)





3 Ordering information

Table 6.Ordering information

Order code	Marking	Package	Weight	Base qty	Delivery mode
STPS30H60CGY-TR	STPS30H60CGY-TR	D ² PAK	1.48 g	1000	Tape and reel

4 Revision history

Table 7.Document revision history

Date	Revision	Changes
20-Mar-2012	1	First issue.



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